# onsemi

## Silicon Photomultipliers (SiPM), Low-Noise, Blue-Sensitive

## **C-Series SiPM Sensors**

The C-Series low-light sensors from **onsemi** feature an industry-leading low dark-count rate combined with a high PDE. For ultrafast timing applications, C-Series sensors have a fast output that can have a rise time of 300 ps and a pulse width of 600 ps. The C-Series is available in different sensor sizes (1 mm, 3 mm and 6 mm) and packaged in a 4-side tileable surface mount (SMT) package that is compatible with industry standard, lead-free, reflow soldering processes.

The C-Series Silicon Photomultipliers (SiPM) form a range of high gain, single-photon sensitive, UV-to-visible light sensors. They have performance characteristics similar to a conventional PMT, while benefiting from the practical advantages of solid-state technology: low operating voltage, excellent temperature stability, robustness, compactness, output uniformity, and low cost. For advice on the usage of these sensors please refer to the <u>Biasing and Readout</u> Application Note.



Figure 1. C-Series Sensors

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 14 of this data sheet.

| Sensor<br>Size | Microcell Size | Parameter (Note 1)  | Overvoltage | Min. | Тур. | Max. | Units |
|----------------|----------------|---|-------------|------|------|------|-------|
| 1 mm           | 10μ, 20μ, 35μ  | Breakdown Voltage (Vbr) (Note 3)                              |             | 24.2 |      | 24.7 | V     |
| 3 mm           | 20μ, 35μ, 50μ  |   |             |      |      |      |       |
| 6 mm           | 35μ            |   |             |      |      |      |       |
| 1 mm           | 10μ, 20μ, 35μ  | Recommended overvoltage Range<br>(Voltage above Vbr) (Note 2) |             | 1.0  |      | 5.0  | V     |
| 3 mm           | 20μ, 35μ, 50μ  |   |             |      |      |      |       |
| 6 mm           | 35μ            |   |             |      |      |      |       |
| 1 mm           | 10μ, 20μ, 35μ  | Spectral Range (Note 4)                                       |             | 300  |      | 950  | nm    |
| 3 mm           | 20μ, 35μ, 50μ  |   |             |      |      |      |       |
| 6 mm           | 35μ            |   |             |      |      |      |       |
| 1 mm           | 10μ, 20μ, 35μ  | Peak Wavelength (λp)  |             |      | 420  |      | nm    |
| 3 mm           | 20μ, 35μ, 50μ  |   |             |      |      |      |       |
| 6 mm           | 35μ            |   |             |      |      |      |       |

#### Table 1. PERFORMANCE PARAMETERS

1

| Sensor<br>Size | Microcell Size | Parameter (Note 1)                 | Overvoltage | Min.            | Тур.            | Max. | Units |
|----------------|----------------|------------------------------------|-------------|-----------------|-----------------|------|-------|
| 1 mm           | 10μ            | PDE (Note 5) at λp                 | Vbr + 2.5 V |                 | 14              | 8    | %     |
|                | 20μ            |                                    |             |                 | 24              |      | %     |
|                | 35μ            |                                    |             | 31              |                 | %    |       |
| 1 mm           | 10μ            |                                    | Vbr + 5.0 V |                 | 18              |      | %     |
|                | 20μ            |                                    |             |                 | 31              |      | %     |
|                | 35μ            | 7                                  |             |                 | 41              |      | %     |
| 3 mm           | 20μ            |                                    | Vbr + 2.5 V |                 | 24              |      | %     |
|                | 35μ            |                                    |             |                 | 31              |      | %     |
|                | 50μ            | 1                                  |             |                 | 35              |      | %     |
| 3 mm           | 20μ            |                                    | Vbr + 5.0 V |                 | 31              |      | %     |
|                | 35μ            |                                    |             |                 | 41              |      | %     |
|                | 50μ            |                                    |             |                 | 47              |      | %     |
| 6 mm           | 35μ            |                                    | Vbr + 2.5 V | 31              |                 |      | %     |
| 6 mm           | 35μ            |                                    | Vbr + 5.0 V |                 | 41              |      | %     |
| 1 mm           | 10μ            | Gain<br>(anode to cathode readout) | Vbr + 2.5 V | $2 \times 10^5$ |                 |      |       |
|                | 20μ            |                                    |             |                 | $1	imes 10^{6}$ |      |       |
|                | 35μ            |                                    |             |                 | $3	imes 10^6$   |      |       |
| 3 mm           | 20μ            |                                    |             |                 | $1	imes 10^{6}$ |      |       |
|                | 35μ            |                                    |             |                 | $3	imes 10^6$   |      |       |
|                | 50μ            | 7                                  |             |                 | $6	imes 10^6$   |      |       |
| 6 mm           | 35μ            |                                    |             |                 | $3	imes 10^6$   |      |       |
| 1 mm           | 10μ            | Dark Current (Note 6)              | Vbr + 2.5 V |                 | 1               | 3    | nA    |
|                | 20μ            | 7                                  |             |                 | 5               | 16   | nA    |
|                | 35μ            | 7                                  |             |                 | 15              | 49   | nA    |
| 3 mm           | 20μ            | 7                                  |             |                 | 50              | 142  | nA    |
|                | 35μ            | 1                                  |             |                 | 154             | 443  | nA    |
|                | 50μ            | 1                                  |             |                 | 319             | 914  | nA    |
| 6 mm           | 35μ            | 7                                  |             |                 | 618             | 1750 | nA    |

#### Table 1. PERFORMANCE PARAMETERS (continued)

#### Sensor Size Parameter (Note 1) **Microcell Size** Overvoltage Min. Тур. Max. Units Vbr + 2.5 V Dark Count Rate 1 mm 10μ 30 kHz 96 20μ 30 96 kHz 35μ 30 96 kHz 3 mm 20µ 300 860 kHz 35μ kHz 300 860 50μ 300 860 kHz 35μ 1200 3400 kHz 6 mm Rise Time - Fast Output (Note 7) 1 mm 10μ, 20μ, 35μ 0.3 ns 20μ, 35μ, 50μ 3 mm 0.6 ns 35μ 6 mm 1.0 ns Signal Pulse Width - Fast Output (FWHM) 10μ, 20μ, 35μ 0.6 1 mm ns 20μ, 35μ, 50μ 3 mm 1.5 ns 35μ 6 mm 3.2 ns 1 mm Microcell recharge time constant (Note 8) 10μ 5 ns 20μ 23 ns 35μ 82 ns 3 mm 20µ 23 ns 35μ 82 ns 50μ 159 ns 35μ 6 mm 95 ns Capacitance (Note 9) Vbr + 2.5 V 1 mm 10μ 50 pF (anode-cathode) pF 20μ 90 35μ 100 pF 3 mm 20µ 770 pF 35μ 850 pF 50μ 920 pF 35μ 6 mm 3400 pF Vbr + 2.5 V 1 mm Capacitance (Note 9) 10μ pF 1 (fast terminal to cathode) 20μ 1 pF 35μ 1 pF

#### Table 1. PERFORMANCE PARAMETERS (continued)

| Sensor<br>Size | Microcell Size | Parameter (Note 1)                                 | Overvoltage | Min. | Тур. | Max. | Units |
|----------------|----------------|--|-------------|------|------|------|-------|
| 3 mm           | 20μ            | Capacitance (Note 9)<br>(fast terminal to cathode) | Vbr + 2.5 V | 20   |      |      | pF    |
|                | 35μ            |  |             |      | 12   |      | pF    |
|                | 50μ            |  |             |      | 7    |      | pF    |
| 6 mm           | 35μ            |  |             | 48   |      |      | pF    |
| 1 mm           | 10μ, 20μ, 35μ  | Temperature dependence of Vbr                      |             |      | 21.5 |      | mV/°C |
| 3 mm           | 20μ, 35μ, 50μ  |  |             |      |      |      |       |
| 6 mm           | 35μ            |  |             |      |      |      |       |
| 1 mm           | 10μ, 20μ, 35μ  | Temperature dependence of Gain (Note 10)           |             |      | -0.8 |      | %/°C  |
| 3 mm           | 20μ, 35μ, 50μ  |  |             |      |      |      |       |
| 6 mm           | 35μ            |  |             |      |      |      |       |
| 1 mm           | 10µ Crosstalk  |  | Vbr + 2.5 V | 0.6  |      |      | %     |
|                | 20μ            | -  |             | 3    |      | %    |       |
|                | 35μ            |  |             | 7    |      | %    |       |
| 3 mm           | 20μ            |  |             |      | 3    |      | %     |
|                | 35μ            |  |             |      | 7    |      | %     |
|                | 50μ            |  |             |      | 10   |      | %     |
| 6 mm           | 35μ            |  |             |      | 7    |      | %     |
| 1 mm           | 10μ            | Afterpulsing                                       | Vbr + 2.5 V |      | 0.2  |      | %     |
|                | 20μ            |  |             |      | 0.2  |      | %     |
|                | 35μ            | 1  |             |      | 0.2  |      | %     |
| 3 mm           | 20μ            | 1  |             |      | 0.2  |      | %     |
|                | 35μ            | 1  |             |      | 0.2  |      | %     |
|                | 50μ            | -  |             |      | 0.6  |      | %     |
| 6 mm           | <b>35</b> μ    |  |             |      | 0.2  |      | %     |

#### Table 1. PERFORMANCE PARAMETERS (continued)

1. All measurements made at 2.5 V overvoltage and 21°C unless otherwise stated.

2. Please consult the maximum current levels on page 6 when selecting the overvoltage to apply.

3. The breakdown voltage (Vbr) is defined as the value of the voltage intercept of a straight line fit to a plot of  $\sqrt{I}$  vs V, where I is the current and V is the bias voltage.

4. The range where PDE > 1% at Vbr + 5.0 V.

5. Note that the PDE does not contain contributions from afterpulsing or crosstalk. 6. Dark current derived from dark count data as  $DC \times M \times q \times (1 + CT)$ , where DC is dark count, M is gain, q is the charge of an electron, and CT is cross talk.

7. Measured as time to go from 10% to 90% of the peak amplitude.

RC charging time constant of the microcell (τ)
 Internal capacitance of the sensor. Typically add 2–3 pF for sensor in package. Listed by unique microcell size for each part version.

10. Quoted as the percentage change per degree C from the measured value at 21°C.

#### **GENERAL PARAMETERS**

#### Table 2. GENERAL PARAMETERS

|                       | 1 mm                                     | 3 mm                                       | 6 mm                      |
|-----------------------|--|--|---------------------------|
|                       | 10010, 10020, 10035                      | 30020, 30035, 30050                        | 60035                     |
| Active area           | $1 \times 1 \text{ mm}^2$                | $3 \times 3 \text{ mm}^2$                  | $6 \times 6 \text{ mm}^2$ |
| No. of microcells     | 10010: 2880<br>10020: 1296<br>10035: 504 | 30020: 10998<br>30035: 4774<br>30050: 2668 | 60035: 18980              |
| Microcell fill factor | 10010: 28%<br>10020: 48%<br>10035: 64%   | 30020: 48%<br>30035: 64%<br>30050: 72%     | 60035: 64%                |

#### Table 3. PACKAGE PARAMETERS

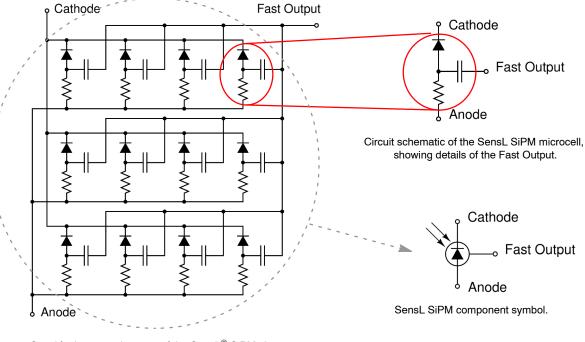
|   | 1 mm  | 3 mm                      | 6 mm                      |  |  |
|---|---|---------------------------|---------------------------|--|--|
|   | 10010, 10020, 10035   | 30020, 30035, 30050       | 60035                     |  |  |
| Package dimensions                      | $1.5 	imes 1.8 \text{ mm}^2$  | $4 \times 4 \text{ mm}^2$ | $7 \times 7 \text{ mm}^2$ |  |  |
| Recommended operating temperature range |   | -40°C to +85°C            |                           |  |  |
| Maximum storage temperature             | +105°C  |                           |                           |  |  |
| Soldering conditions                    | Lead-free, reflow soldering process compatible<br>(MSL 3 for tape & reel quantities; MSL 4 for tape only qty.)<br>See the <u>SMT Handling Tech Note</u> for more details. |                           |                           |  |  |
| Encapsulant type                        | Clear transfer molding compound   |                           |                           |  |  |
| Encapsulant refractive Index            | 1.59 @ 420 nm   |                           |                           |  |  |

#### Table 4. MAXIMUM CURRENT LEVELS FOR EACH SENSOR SIZE

| 1 mm                | 3 mm                | 6 mm  |
|---------------------|---------------------|-------|
| 10010, 10020, 10035 | 30020, 30035, 30050 | 60035 |
| 6 mA                | 15 mA               | 20 mA |

#### **CIRCUIT SCHEMATICS**

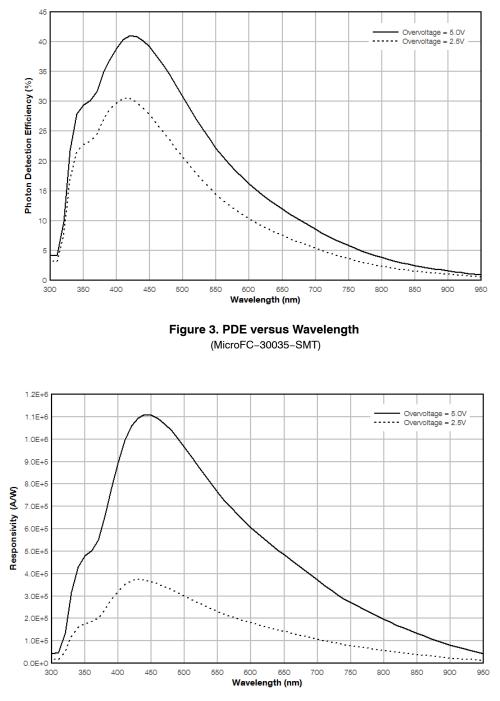
An SiPM is formed of a large number (hundreds or thousands) of microcells. Each microcell is an avalanche photodiode with its own quench resistor and a capacitively coupled fast output. These microcells are arranged in a close-packed array with all of the like terminals (e.g. all of the anodes) summed together. The array of microcells can thus be considered as a single photodiode sensor with three terminals: anode, cathode and fast output.

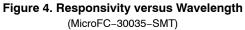


Simplified circuit schematic of the SensL<sup>®</sup> SiPM showing only a 12 microcell example. Typically, SiPM sensors have hundreds or thousands of microcells.

Figure 2. Circuit Schematic







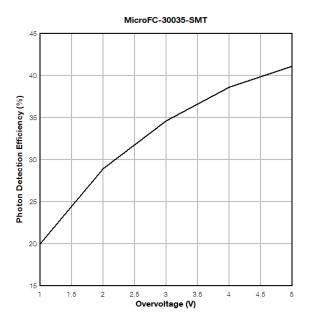
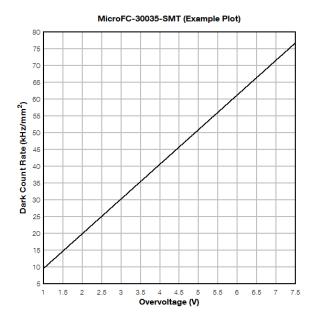


Figure 5. PDE at 420 nm versus Voltage





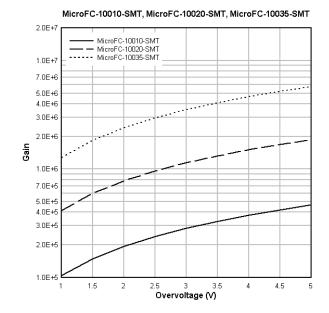
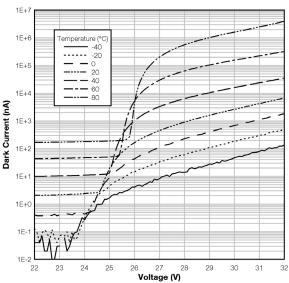


Figure 7. Gain versus Overvoltage



Voltage (V)

Figure 8. Dark Current versus Voltage and Temperature

MicroFC-60035-SMT

#### **EVALUATION BOARD OPTIONS**

#### SMA Biasing Board (MicroFC-SMA-XXXXX)

The MicroFC–SMA is a printed circuit board (PCB) that can facilitate the evaluation of the C–Series SMT sensors. The board has three female SMA connectors for connecting the bias voltage, the standard output from the anode and the fast output signal. The output signals can be connected directly to a 50  $\Omega$ -terminated oscilloscope for viewing. The biasing and output signal tracks are laid out in such a way as to preserve the fast timing characteristics of the sensor.

The MicroFC–SMA is recommended for users who require a plug-and-play set-up to quickly evaluate C–Series SMT sensors with optimum timing performance. The board also allows the standard output from the anode-cathode readout to be observed at the same time as the fast output. The outputs can be connected directly to the oscilloscope or measurement device, but external preamplification may be required to boost the signal. The table below lists the SMA board connections. The SMA board electrical schematics are available to download in <u>AND9809/D</u>.

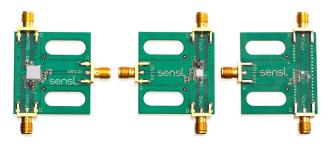


Figure 9. SMA Biasing Board

| MicroFC-SMA-XXXXX |                               |  |  |  |  |
|-------------------|-------------------------------|--|--|--|--|
| Output            | Function                      |  |  |  |  |
| Vbias             | Positive bias input (cathode) |  |  |  |  |
| Fout              | Fast output                   |  |  |  |  |
| Sout              | Standard output (anode)       |  |  |  |  |

#### Pin Adapter (MicroFC-SMTPA-XXXXX)

The SMT Pin Adapter board (SMTPA) is a small PCB board that houses the SMT sensor and has through-hole pins to allow for use with standard sockets or probe clips. This product is useful for those needing a quick way to evaluate the C–Series SMT sensors without the need for specialist surface-mount soldering. While this is a 'quick fix' suitable for many evaluations, it should be noted that the timing performance from this board will not be optimized and if the best possible timing performance is required, the MicroFC–SMA–XXXXX is recommended. The pin-out

information is shown in the table below. The SMTPA board electrical schematics are shown in Figure 12 and are available to download in <u>AND9809/D</u>.

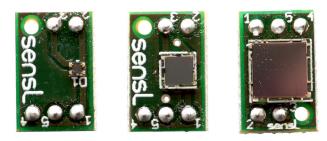


Figure 10. Pin Adapter

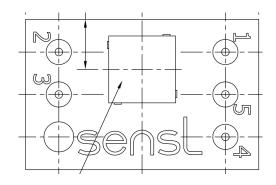


Figure 11. MicroFC-SMTPA-XXXXX

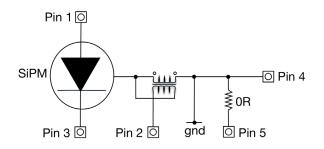


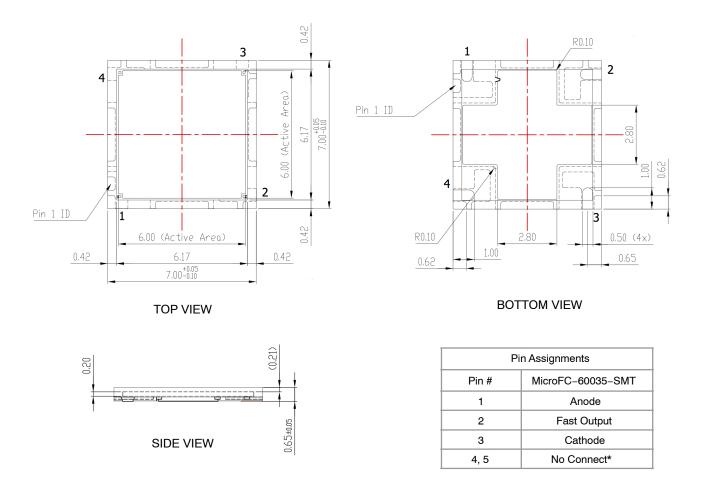
Figure 12. SMTPA Board Circuit Schematic

| MicroFC-SMTPA-XXXXX |             |  |  |  |
|---------------------|-------------|--|--|--|
| Pin No.             | Connection  |  |  |  |
| 1                   | Anode       |  |  |  |
| 2                   | Fast output |  |  |  |
| 3                   | Cathode     |  |  |  |
| 4                   | Ground      |  |  |  |
| 5                   | No connect  |  |  |  |

#### PACKAGE DIMENSIONS

(All Dimensions in mm)

MicroFC-60035-SMT



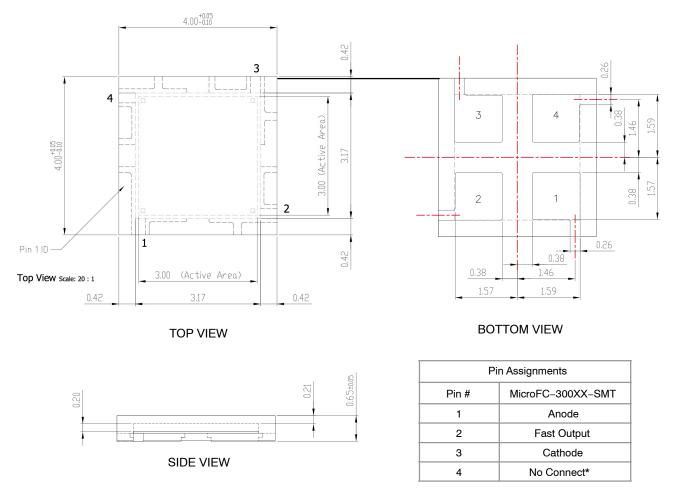
\*The 'No Connect' pin 4 should be soldered to the PCB. This pin can be connected to ground but it can also be left floating without affecting the dark noise. It is recommended that the Pin 5 paddle is NOT soldered to the PCB and is left floating to achieve optimal soldering on pins 1 to 4. Please note the full advice in the CAD file.

The complete MicroFC-60035-SMT POD is available to download here.

#### PACKAGE DIMENSIONS

(All Dimensions in mm)

#### MicroFC-30020-SMT, MicroFC-30035-SMT, MicroFC-30050-SMT



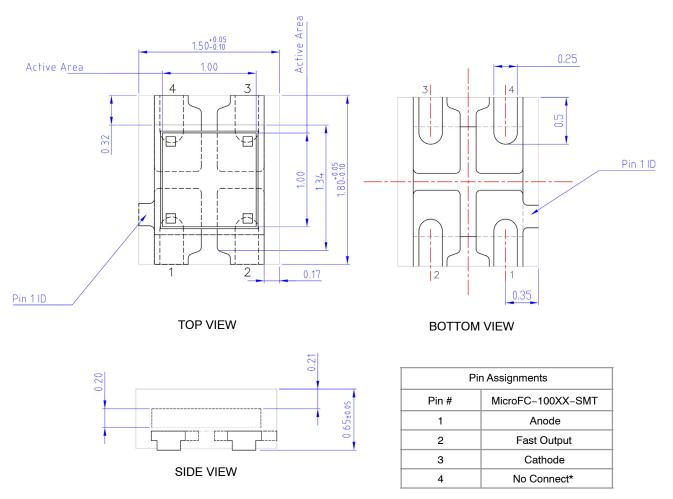
\*The 'No Connect' pin 4 should be soldered to the PCB. It can be connected to ground but it can also be left floating without affecting the dark noise.

The complete MicroFC-300xx-SMT POD is available to download here.

#### PACKAGE DIMENSIONS

(All Dimensions in mm)

#### MicroFC-10010-SMT, MicroFC-10020-SMT & MicroFC-10035-SMT



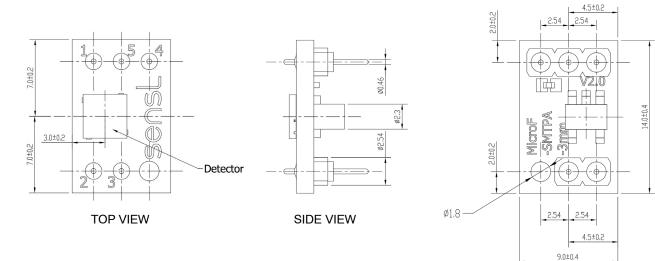
\*The 'No Connect' pin 4 should be soldered to the PCB. It can be connected to ground but it can also be left floating without affecting the dark noise.

The complete MicroFC-100XX-SMT POD is available to download here.

#### PACKAGE DIMENSIONS

(All Dimensions in mm)

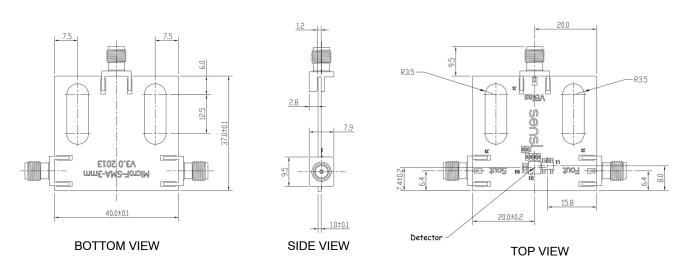
#### MicroFC-SMTPA Board



BOTTOM VIEW

The electrical schematics for the SMTPA board is available in <u>AND9809/D</u>.

MicroFC-SMA Board



The electrical schematics for the SMA board is available in AND9809/D.

#### **USEFUL LINKS**

- Introduction to Silicon Photomultipliers Application Note If you are new to SiPM, this document explains their operation and main performance parameters.
- <u>Biasing and Readout Application Note</u> This document gives detailed information on how to bias the sensor for both standard and fast configurations, and amplifying and reading out the signal.
- <u>How to Evaluate and Compare Silicon Photomultipliers Application Note</u> Information on what to consider when selecting an SiPM.
- <u>Handling and Soldering Guide</u> This document gives information on safe handling of the sensors and soldering to PCB.

#### **ORDERING INFORMATION**

#### Table 5. ORDERING INFORMATION

| Product Code<br>(Note 11) | Microcell Size<br>(Total Number) | Sensor<br>Active Area | Package Type   | Delivery<br>Options<br>(Note 12) |
|---------------------------|----------------------------------|-----------------------|--|----------------------------------|
| 10000 Series              |                                  |                       |  |                                  |
| MICROFC-10010-SMT         | 10 μm<br>(2880 microcells)       | 1 mm × 1 mm           | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-10010-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-10010-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board.                           | РК                               |
| MICROFC-10020-SMT         | 20 μm<br>(1296 microcells)       |                       | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-10020-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-10020-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board.                           | PK                               |
| MICROFC-10035-SMT         | 35 μm<br>(504 microcells)        |                       | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-10035-GEVB    | 1                                |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-10035-GEVB  | 1                                |                       | SMT sensor mounted onto a pin adapter board.                           | PK                               |

#### Table 5. ORDERING INFORMATION (continued)

| Product Code<br>(Note 11) | Microcell Size<br>(Total Number) | Sensor<br>Active Area | Package Type   | Delivery<br>Options<br>(Note 12) |
|---------------------------|----------------------------------|-----------------------|--|----------------------------------|
| 0000 Series               |                                  |                       |  |                                  |
| MICROFC-30020-SMT         | 20 μm<br>(10998 microcells)      | 3 mm × 3 mm           | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-30020-GEVB    | -                                |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-30020-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board                            | PK                               |
| MICROFC-30035-SMT         | 35 μm<br>(4774 microcells)       |                       | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-30035-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-30035-GEVB  |                                  |                       | SMT sensor mounted onto a pin adapter board                            | PK                               |
| MICROFC-30050-SMT         | 50 μm<br>(2668 microcells)       |                       | 4-side tileable, surface mount package (SMT)                           | TR1, TR                          |
| MICROFC-SMA-30050-GEVB    |                                  |                       | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK                               |
| MICROFC-SMTPA-30050-GEVB  | 1                                |                       | SMT sensor mounted onto a pin adapter board                            | PK                               |

#### 60000 Series

| MICROFC-60035-SMT        | 35 μm<br>(18980 microcells) | 6mm × 6mm | 4-side tileable, surface mount package<br>(SMT)                        | TR1, TR |
|--------------------------|-----------------------------|-----------|--|---------|
| MICROFC-SMA-60035-GEVB   |                             |           | SMT sensor mounted onto a PCB with SMA connectors for bias and output. | PK      |
| MICROFC-SMTPA-60035-GEVB |                             |           | SMT sensor mounted onto a pin<br>adapter board                         | PK      |

11. All Devices are Pb-Free and are RoHS Compliant.

12. The two-letter delivery option code should be appended to the order number, e.g.) to receive MICROFC-60035-SMT on tape and reel, use MICROFC-60035-SMT-TR. The codes are as follows:

PK = ESD Package

TR1 = Tape

TR = Tape and Reel

There is a minimum order quantity (MOQ) of 3000 for the tape and reel (TR) option. The TR option is only available in multiples of the MOQ.

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